NSN 5961-01-335-3460

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-335-3460 **Inclosure Material:** Ceramic **Overall Length:** 0.090 inches **Terminal Length:** 0.200 inches **Overall Height:** 0.030 inches **Overall Width:** 0.045 inches **End Application:** 6625-01-289-1998 counter frequency **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 source to substrate voltage **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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